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Amorphization engineered VSe_{2-x} nanosheets with abundant Se-vacancies for enhanced N_2 electroreduction†Yaojing Luo,^{‡a} Qingqing Li,^{‡a} Ye Tian,[Ⓜ] Yaping Liu,[Ⓜ]†^a and Ke Chu,[Ⓜ]†^{*a}

Electrochemical N_2 fixation through the nitrogen reduction reaction (NRR) is a promising route for sustainable NH_3 synthesis, while exploring high-performance NRR catalysts lies at the heart of achieving high-efficiency NRR electrocatalysis. Herein, we reported the structural regulation of VSe_2 by amorphization engineering, which simultaneously triggered the enriched Se-vacancies. The developed amorphous VSe_{2-x} nanosheets with abundant Se-vacancies (a- VSe_{2-x}) delivered a much enhanced NRR activity with an NH_3 yield of $65.7 \mu g h^{-1} mg^{-1}$ and a faradaic efficiency of 16.3% at $-0.4 V$, being 8.8- and 3.5-fold higher than those of their crystalline counterparts, respectively. Density functional theory computations combined with molecular dynamics simulations revealed that the amorphization-triggered Se-vacancies could induce the upraised d-band center of unsaturated V atoms, capable of promoting the binding of key $*N_2$ / $*NNH$ species to result in an energetically favorable NRR process.

Nitrogen fixation to ammonia is a vital chemical process since NH_3 is a crucial nitrogen source for producing fertilizers and is also a highly viable chemical energy carrier.¹⁻³ However, the Haber-Bosch (H-B) process for industrial N_2 fixation is performed under high temperature and pressure conditions, which entail a large burden for global energy consumption.⁴⁻⁶ Meanwhile, the hydrogen feedstock of the H-B process primarily originates from coal gasification and methane reforming which causes severe CO_2 emissions.⁷ Alternatively, electrochemical N_2 fixation through the nitrogen reduction reaction (NRR) has gained noticeable popularity as a promising route for sustainable NH_3 synthesis.⁸⁻¹⁵ Despite recent progress, the electrocatalytic NRR properties in terms of the NH_3 production rate and N_2 -to- NH_3 faradaic efficiency still fall short of the practical

implementation, arising from the low N_2 solubility in aqueous electrolyte, sluggish $N\equiv N$ bond dissociation kinetics and competitive hydrogen evolution reaction (HER).¹⁶⁻²⁹ Thus, it is of great significance to explore advanced electrocatalysts that can reduce the energy barriers for $N\equiv N$ bond activation and prohibit the occurrence of the HER simultaneously.³⁰⁻⁴²

Transition metal selenides have emerged as promising electrocatalysts by virtue of their intriguing physicochemical properties, tunable electronic structure, facile synthesis and good durability.⁴³ Although selenides have been extensively investigated for a series of electrocatalytic reactions,⁴⁴⁻⁴⁶ studies on selenides are rarely related to the electrocatalytic NRR to date. In addition, the NRR activity of the earlier reported selenides is still far from satisfactory,⁴⁷ leaving much room for further improvement. Amorphization engineering by brokering the atomic long-range order has been regarded as one of the effective strategies for fine-tuning the catalyst electronic structure towards improved catalytic performance.⁴⁸⁻⁵¹ The amorphous electrocatalysts exhibit the enhanced NRR activity with respect to their crystalline counterparts, attributed primarily to the amorphization-induced unsaturated electronic configuration which promotes the N_2 adsorption/activation and optimizes the binding energies of reaction intermediates for the efficient NRR process. Inspired by this, the amorphization engineering may provide the feasibility for regulating the structure and electronic configuration of selenides to achieve the potentially high NRR performance.

Here, we report an amorphization engineering strategy to improve the NRR activity and selectivity of VSe_2 . Supercritical CO_2 (SC- CO_2) treatment was utilized to transform crystalline VSe_2 nanosheets into amorphous ones composed of abundant Se-vacancies (a- VSe_{2-x}). Such a- VSe_{2-x} exhibited an attractive NRR activity with an NH_3 yield of $65.7 \mu g h^{-1} mg^{-1}$ and an FE of 16.3% at $-0.4 V$, far better than those of their crystalline counterparts. The electronic structure and NRR mechanism of a- VSe_{2-x} were further unraveled by the density functional theory (DFT) calculations and molecular dynamics (MD) simulations.

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The crystalline VSe_2 nanosheets (c-VSe_2) were first prepared by a facile solvothermal method. As a low-cost and non-flammable reaction solvent, SC-CO_2 has unique properties of low viscosity, high diffusion coefficients and good wetting of surfaces, which can be used for liquid exfoliation, phase engineering, and the preparation of amorphous materials.⁵² During the SC-CO_2 treatment process, the SC-CO_2 molecules can easily penetrate into the crystal layers of c-VSe_2 due to the high diffusion coefficients of SC-CO_2 and the assistance of external pressure. Meanwhile, water molecules can also be carried by SC-CO_2 and transferred into the layers of c-VSe_2 .^{52,53} With the increase in the number of impregnating SC-CO_2 and water molecules at the interlayer of c-VSe_2 , the periodic atom arrangement of c-VSe_2 can be destroyed, leading to the crystal-to-amorphous phase conversion with simultaneous removal of

plentiful Se atoms,⁵⁴ obtaining a-VSe_{2-x} . The transmission electron microscopy (TEM) images show that both c-VSe_2 (Fig. 1a) and a-VSe_{2-x} (Fig. 1b) present a typical two-dimensional (2D) sheet-like morphology, indicating that amorphization does not change the original 2D morphology of c-VSe_2 , whereas the structural differences between c-VSe_2 and a-VSe_{2-x} are unveiled by selected area electron diffraction (SAED), X-ray diffraction (XRD) and high-resolution TEM (HRTEM) characterization studies.

The SAED pattern of c-VSe_2 (Fig. 1c) shows well-defined spots, while a halo feature is presented by a-VSe_{2-x} (Fig. 1d), indicating its amorphous structure. As revealed by the XRD patterns (Fig. 1e), in comparison with the distinct diffraction peaks of c-VSe_2 , no obvious peaks are found for a-VSe_{2-x} , indicative of its amorphous phase. The elemental mapping



Fig. 1 (a and b) TEM images of c-VSe_2 and a-VSe_{2-x} at various magnifications. (c and d) SAED patterns of c-VSe_2 and a-VSe_{2-x} . (e) XRD patterns of c-VSe_2 and a-VSe_{2-x} . (f) Elemental mapping images of a-VSe_{2-x} . (g and h) HRTEM images of c-VSe_2 and a-VSe_{2-x} (inset: atomic structure models) and corresponding FFT, IFFT and lattice line scanning analyses (panel A–F).

images of $a\text{-VSe}_{2-x}$ (Fig. 1f) show the uniform distribution of V and Se elements over the entire nanosheets. Further, the HRTEM image of $c\text{-VSe}_2$ (Fig. 1g) shows the well-resolved lattice fringes with a d spacing of 0.26 nm, corresponding to the (011) facet of $a\text{-VSe}_{2-x}$. A randomly selected region in the HRTEM image of $c\text{-VSe}_2$ is further analyzed by Fast Fourier Transform (FFT) and Inverse Fast Fourier Transform (IFFT),^{55–57} showing the diffraction dots (FFT, panel A) and crisscross lattice stripes (IFFT, panel B). Further lattice line scanning analysis (panel C) reveals the periodically arranged lattice atoms. All these HRTEM-related analyses verify the highly crystalline structure of $c\text{-VSe}_2$. In stark contrast, the HRTEM image of $a\text{-VSe}_{2-x}$ (Fig. 1h) shows a rather disordered lattice structure. The corresponding FFT/IFFT analyses show the sun-like pattern (FFT, panel D) and turbostratic structure (IFFT, panel E),⁵¹ suggesting the amorphous structure of $a\text{-VSe}_{2-x}$. The lattice line scanning analysis (panel F) reveals the loss of many lattice atoms (dotted circles), implying the generation of enriched vacancies on $a\text{-VSe}_{2-x}$. The elemental analysis of $a\text{-VSe}_{2-x}$ unravels a reduced Se/V molar ratio of 1.82 (1.75 for $a\text{-VSe}_{2-x}$ and 1.98 for $c\text{-VSe}_2$

based on the XPS analyses) relative to its nominal ratio (2), suggesting the Se-deficient nature of $a\text{-VSe}_{2-x}$ which comprise abundant Se-vacancies.

X-Ray photoelectron spectroscopy (XPS) is used to investigate the electronic bonding states. For both $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$, the V 2p spectra (Fig. 2a) show two V 2p_{3/2} and V 2p_{1/2} peaks centered at ~515.5 and ~523.1 eV, respectively. The deconvoluted peaks at 54.5 and 55.3 eV are associated with the Se 3d state (Fig. 2b). Obviously, both V 2p and Se 3d spectra of $a\text{-VSe}_{2-x}$ are found to present an obvious peak-shift toward the low binding energies compared to those of $c\text{-VSe}_2$. The increased electronic states of $a\text{-VSe}_{2-x}$ are mainly caused by the amorphization-triggered Se-vacancies. The electron paramagnetic resonance (EPR, Fig. 2c) spectroscopy shows that $a\text{-VSe}_{2-x}$ exhibits a much stronger EPR signal than $c\text{-VSe}_2$, further confirming the amounts of Se-vacancies generated on $a\text{-VSe}_{2-x}$.

DFT calculations are performed to investigate the electronic structures of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. According to the electron localization function (ELF) images sliced along the (001) plane,

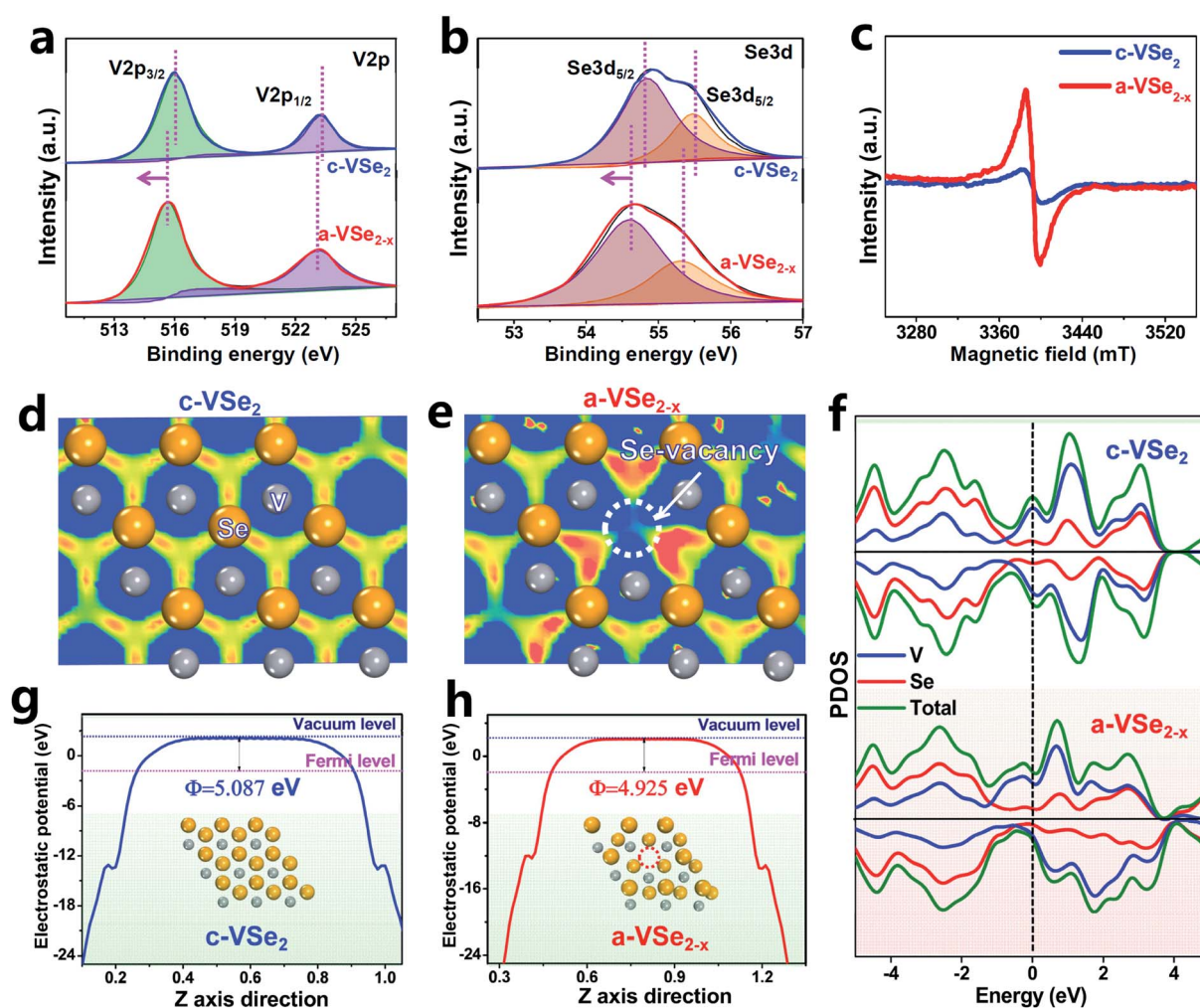


Fig. 2 (a) XPS V 2p spectra of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. (b) XPS Se 3d spectra of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. (c) EPR spectra of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. (d and e) Electron localization function images of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. Blue and red regions represent the electron depletion and accumulation, respectively. (f) PDOS of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$. (g and h) Average potential profiles of $c\text{-VSe}_2$ and $a\text{-VSe}_{2-x}$.

c-VSe₂ (Fig. 2d) displays an electron localization feature with a uniform distribution of electrons around V atoms. As for a-VSe_{2-x} (Fig. 2e), the electrons tend to flow toward Se-vacancies, leading to the delocalized electron gathering at the Se-vacancy region. Such Se-vacancy-induced delocalized electrons are most likely transferred into the antibonding orbitals of N₂ molecules for polarization of the N≡N covalent bond.⁵⁸ As illustrated by the projected density of states (PDOS, Fig. 2f), both c-VSe₂ and a-VSe_{2-x} deliver higher occupied states across the Fermi level, suggesting their high conductivity which is favorable for accelerated proton-coupled electron transfer. This can also be experimentally confirmed by electrochemical impedance spectroscopy (EIS, Fig. S1†). The good conductivity of c-VSe₂ and a-VSe_{2-x} is mainly attributed to the strong electron coupling interactions involved in V₄⁺-V₄⁺ pairs of VSe₂ inducing the metallic properties.⁴³ Additionally, in contrast to the symmetry spin-up/spin-down states of c-VSe₂, the spin-up and spin-down states are asymmetrical for a-VSe_{2-x}, manifesting that a-VSe_{2-x} is spin-polarized with the existence of magnetic spin moments.⁵⁹ The spin moments of a-VSe_{2-x} can loosen the orbital electrons in the N≡N covalent bond, favorable for activating and polarizing the N₂ molecules.⁵⁹ Moreover, the average potential profiles reveal that a-VSe_{2-x} has a lower work function (4.925 eV, Fig. 2g) than c-VSe₂ (5.087 eV, Fig. 2h), indicating that a-VSe_{2-x} has higher electronic energy levels and

a stronger electron-donating ability to enhance the π back-donation and promote the NRR activity.⁶⁰⁻⁶²

Electrochemical NRR measurements are performed in N₂-saturated 0.5 M LiClO₄ solution in a gas-tight two-compartment electrolytic cell.³⁹ All potentials reported in this work were converted to the reversible hydrogen electrode (RHE) scale. Prior to NRR tests, all feed gases are purified through acid/alkaline traps to remove any possible NO_x contaminants (Fig. S2†).⁶³ As shown in the linear sweep voltammetry (LSV, Fig. S3†) curves, a cathodic current onset is present at around -0.2 V due to the occurrence of the HER in both Ar and N₂ saturated electrolytes, while N₂ electrolyte presents a noticeably higher current density than Ar solution, confirming the feasibility of a-VSe_{2-x} for N₂ electroreduction. When the potential becomes more negative, the LSV curves in Ar and N₂ saturated electrolytes gradually coincide due to the enhanced HER that dominates the electrode process.²⁹ Electrolysis for quantitatively evaluating the NRR performance of a-VSe_{2-x} is conducted by chronoamperometry at various potentials for 2 h (Fig. 3a). The produced NH₃ in each resulting electrolyte is analyzed by a colorimetric method (Fig. S4†). Fig. 3b shows the corresponding UV-vis absorption spectra of the electrolytes stained with an indophenol indicator, and the calculated data of NH₃ yields and FEs are plotted in Fig. 3c. Notably, a-VSe_{2-x} attains the highest NH₃ yield (65.7 $\mu\text{g h}^{-1} \text{mg}^{-1}$) and FE (16.3%) at

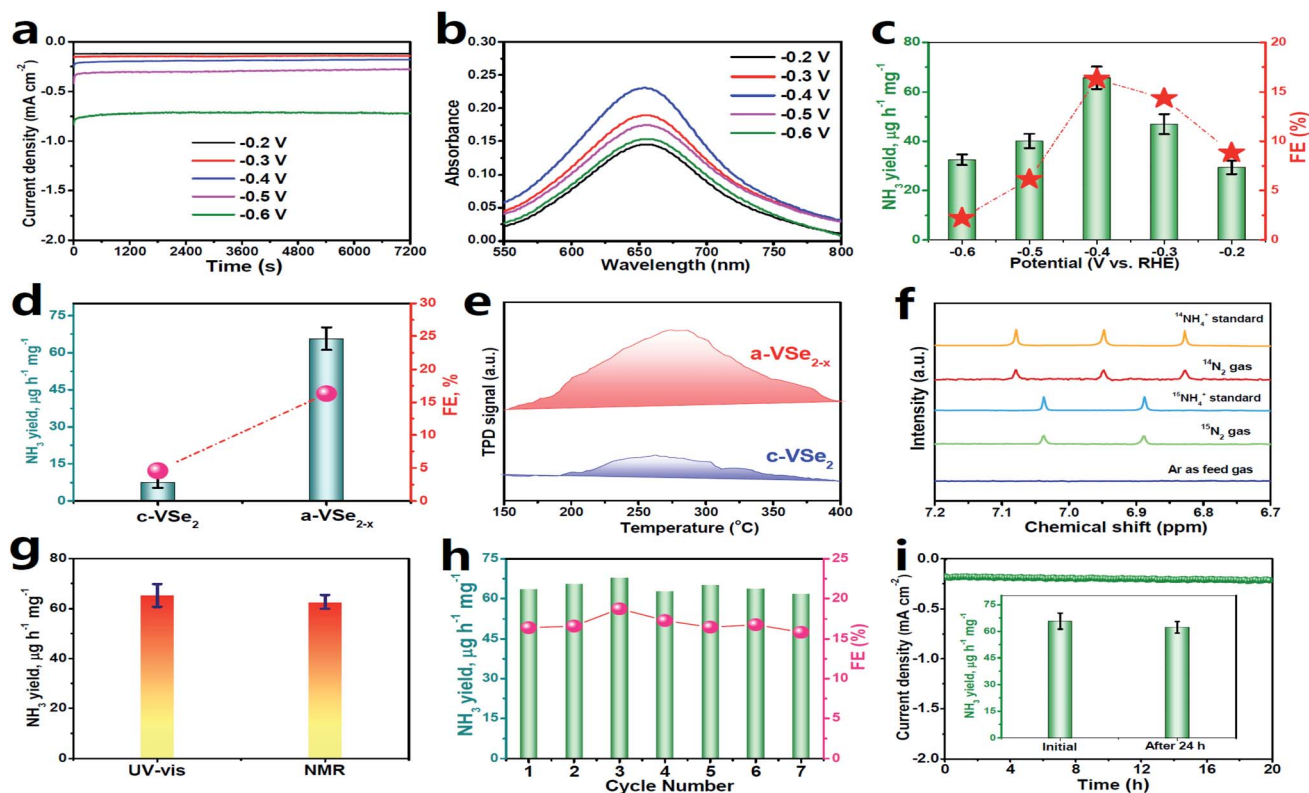


Fig. 3 (a) Chronoamperometry curves of a-VSe_{2-x} at various potentials after 2 h of NRR electrocatalysis, corresponding (b) UV-vis absorption spectra, and (c) obtained NH₃ yields and FEs. (d) Comparison of the NH₃ yields/FEs of c-VSe₂ and a-VSe_{2-x}. (e) N₂-TPD spectra of c-VSe₂ and a-VSe_{2-x}. (f) Isotope-labeling NMR spectra of the electrolytes fed by ¹⁵N₂/¹⁴N₂ and Ar gases. (g) Comparison of NH₃ yields by UV-vis and NMR tests (Fig. S9†). (h) Cycling test. (i) Chronoamperometry test for 24 h (inset: NH₃ yields of initial and post-NRR electrolysis). (d and f–i) are performed at -0.4 V.

Moreover, an N_2 -Ar gas switching experiment (Fig. S10[†]) shows that the NH_3 products are only obtained in the periods of N_2 -saturated electrolyte, evidencing the electrocatalytic NRR process. All these control experiments unequivocally validate the N_2 -to- NH_3 electroreduction.

The stability of a catalyst in the electrolysis process also represents a critical factor for practical applications. For the consecutive seven cycles of electrolysis (Fig. 3h), no considerable fluctuations in NH_3 yield/FEs can be found, implying the good cycling stability of a- VSe_{2-x} . In addition, the chronoamperometry test for 24 h of continuous NRR electrolysis (Fig. 3i) shows a steady current density with no significant decay, and the corresponding NH_3 yield (Fig. 3i, inset) exhibits a very small change with respect to the initial one, proving the excellent long-term durability of a- VSe_{2-x} . Moreover, no obvious change in the structure of a- VSe_{2-x} for the post-NRR is found in terms of XRD (Fig. S11[†]), TEM (Fig. S12[†]) and XPS (Fig. S13[†]) characterization studies, signifying the good structural durability.

Theoretical investigations are carried out to provide more insights into the NRR mechanism of a- VSe_{2-x} . Fig. 4a shows that c- VSe_2 exhibits a weak N_2 adsorption with an ignorable N-N elongation (1.11 Å). The poor N_2 adsorption is also found for amorphous VSe_2 without Se-vacancies (Fig. S14[†]). With Se-vacancies on a- VSe_{2-x} (Fig. 4b), however, N_2 can be favorably trapped into the Se-vacancy site where $*N_2$ is bonded with three unsaturated V atoms to generate a trinuclear side-on coordinated configuration (Fig. S15[†]). Electron deformation density (Fig. 4c) displays the distinct charge accumulation and depletion around $*N_2$ and its adjacent unsaturated V atoms, suggesting that Se-vacancies on a- VSe_{2-x} play a crucial role in creating unsaturated V atoms as electron back-donation centers for effective N_2 activation. The PDOS analysis (Fig. 4d) shows that a- VSe_{2-x} presents an upshift of the d-band center (unsaturated V atoms), suggesting that the antibonding states between unsaturated V atoms of a- VSe_{2-x} and adsorbed intermediates are less occupied, resulting in their enhanced binding strength. In this scenario, the V-3d orbital of a- VSe_{2-x} can favorably interact with the N_2 -2p orbital to generate hybrid states that facilitate the sufficient adsorption and activation of N_2 (Fig. S16[†]). Thermodynamically speaking, $*NNH$ is generally deemed as a key intermediate for the NRR protonation process.^{21,39,64} With the strong N_2 activation over a- VSe_{2-x} , a prominent charge interaction can also be found between $*NNH$ and unsaturated V atoms (Fig. S17[†]), leading to the effective $*NNH$ stabilization. The favorable stabilization of $*N_2$ / $*NNH$ species over a- VSe_{2-x} can also be confirmed by the MD simulations (Fig. 4e and S18[†]), showing that a- VSe_{2-x} simulation systems display stronger N_2 -catalyst and NNH -catalyst interactions (Fig. 4f, corresponding to a higher radial distribution function (RDF)) with respect to their c- VSe_2 counterparts. Therefore, the amorphization-triggered Se-vacancies can induce the upraised d-band center of unsaturated V atoms to promote N_2 activation and $*NNH$ stabilization, favorable for the expedited NRR activity of a- VSe_{2-x} .

The Gibbs free energies for all the NRR reaction steps are explored on c- VSe_2 and a- VSe_{2-x} (Fig. 4g). Based on their

respective energetically favorable NRR pathways (alternating pathway for c- VSe_2 (Fig. S19[†]) and consecutive for a- VSe_{2-x} (Fig. S20[†])),⁶⁵ the transition from $*N_2$ to $*NNH$ is determined to be the rate-determining step (RDS) for both c- VSe_2 and a- VSe_{2-x} . The large RDS energy barrier (2.21 eV) of c- VSe_2 implies its sluggish hydrogenation process with low NRR activity. Remarkably, the RDS energy barrier of a- VSe_{2-x} is largely decreased to 0.96 eV, indicating more favorable NRR energetics and enhanced NRR activity on a- VSe_{2-x} . The much reduced RDS barrier of a- VSe_{2-x} is attributed to the enhanced binding of key $*N_2$ / $*NNH$ species derived from the Se-vacancy-induced upshift of the d-band center for active unsaturated V atoms. Considering the competitive reaction of H_2 evolution, we finally examine the HER activity by estimating the limiting potential difference between the NRR and HER ($U_L(NRR) - U_L(HER)$) which is a good indicator for assessing the NRR selectivity.⁶⁶ The more positive $U_L(NRR) - U_L(HER)$ implies a higher NRR selectivity. As displayed in Fig. 4h, a- VSe_{2-x} presents a more positive $U_L(NRR) - U_L(HER)$ than c- VSe_2 , suggesting a- VSe_{2-x} can effectively alleviate the competition from the HER. Therefore, the amorphization-triggered Se-vacancies can boost the NRR and impede the HER synchronously, rendering a- VSe_{2-x} with high NRR activity and selectivity.

In summary, a- VSe_{2-x} has been verified to be a highly active and selective NRR catalyst, significantly outperforming the c- VSe_2 counterpart, together with the favorable cycling and long-term stability. Theoretical investigations revealed that the largely enhanced NRR activity of a- VSe_{2-x} originated from the amorphization-triggered Se-vacancies that could induce the upraised d-band center of unsaturated V atoms, promoting the NRR and impeding the HER synchronously. This work underscores the combined amorphization/vacancy engineering for exploring highly active and selective catalysts for N_2 -to- NH_3 electrocatalysis.

Conflicts of interest

There are no conflicts of interest to declare.

Acknowledgements

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